LED760/840-05A Bi-Color LED for medical analysis

LED760/840-05A consists of DDH structure AlGaAs LEDs mounted on a lead frame with a clear epoxy lens. On forward bias it emits a band of visible light, which peaks at 760 nm and 840 nm with common anode.

outer dimension (unit: mm)

Features

High Reliability High Power Common Anode Second emission free

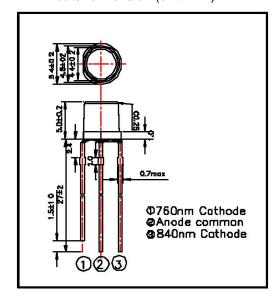
Specifications

Product Name Bi-color LED Type No. L760/840-05A

Chip Material AlGaAs (DDH structure)

Peak wavelength at 760 nm and 840 nm

5mm clear epoxy Epoxy resin material Soldered lead frame



Absolute Maximum Ratings

ltem	Symbol	Maximum Rated Valu 760nm 840nm		Unit	Ambient Temperature
Power Dissipation	P D	200	160	mW	Ta=25°C
Forward Current	īF"	100		mΑ	Ta=25°C
Reverse Voltage	I R	10		V	Ta=25°C
Operating Temperature	TOPR	-30 ~ +85		ů	
Storage Temperature	TSTG	-30 ~ +100		Ŝ	
Soldering Temperature	TSOL	260		ç	

[‡]Soldering condition: Soldering condition must be completed within 3 seconds at 260°C

Electro-Optical Characteristics [Ta = 25°C]

ltem	Symbol	Condition	Minimum		Typical		Maximum		Unit
			760nm	840nm	760nm	840nm	760nm	840nm	
Forward Voltage	VF	lF=50mA			1.85	1.55	2.00	1.70	V
Reverse Current	I R	VR=5V					10		uA
Total Radiated Power	PO	IF=50mA	6.0	10.0	15.0	18.0			mW
Peak Wavelength	λР	lF=50mA	740	820	760	840	780	860	nm
Half Width	Δλ	IF=50mA			30	35			nm
Viewing Half Angle	⊕ 1 <i>/</i> 2	l⊧=50mA			±4	40		·	deg.

[‡]Total Radiated Power is measured by Photodyne #500 ‡Radiant Intensity is measured by Tektronix J-6512

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